

AS1330

4MHz, Low Voltage, DC-DC Step-Up Converter

1 General Description

The AS1330 is a synchronous, low voltage, high efficiency DC-DC boost converter running at a constant frequency of 4MHz. This very high oscillator frequency allows the usage of a very small and low profile inductor with only 470nH. This results in a board space requirement of only 43mm² for the complete solutions including all external components.

AS1330 generates an output voltage between 1.8 and 3.3V from input voltages down to 0.6V. Therefore it is ideal for application powered by a single cell battery. AS1330 provides an output current of 150mA @ 3.3V from a single cell.

To support high efficiency across the entire load range the AS1330 is equipped with a synchronous rectifier and features a power save mode for light loads.

To avoid harmful deep discharge of the battery during shutdown the AS1330 is equipped with an output disconnect function.

AS1330 can either monitor the battery voltage (Sense pin) or report the status of the output voltage (POK).

The AS1330 is available in a TDFN (2x2mm) 8-pin package.

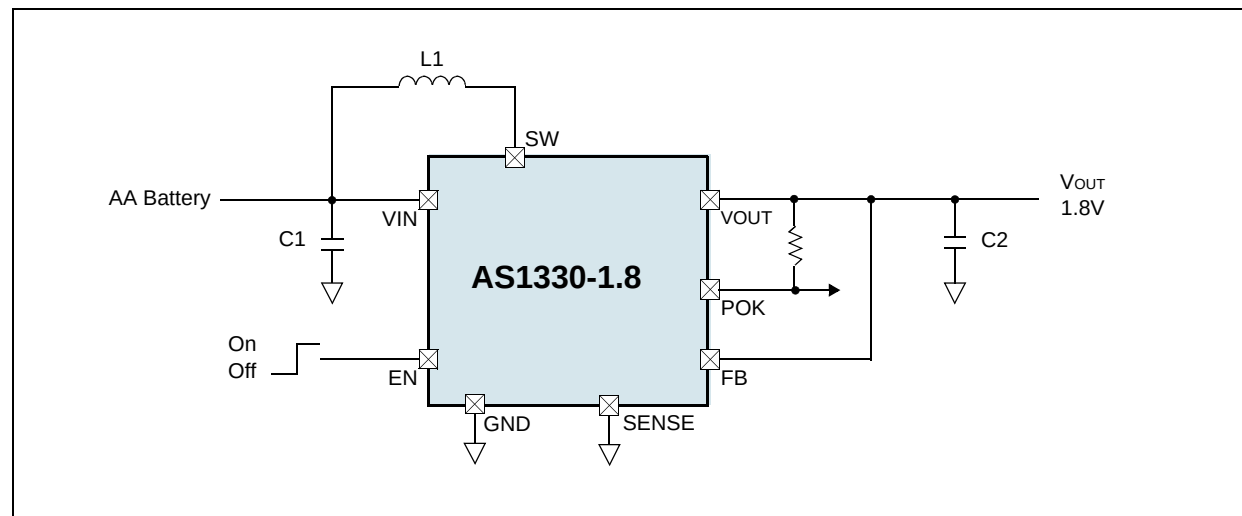
2 Key Features

- Input Voltage Range: 0.6V to 3.0V
- Adjustable Output Voltage Range: 1.8V to 3.3V
- Fixed Output Voltage: 1.8V, 3.0V
- 0.85V Low Start-Up Voltage
- 4MHz Fixed-Frequency
- 91% Efficiency
- Delivers 150mA @ 3.3V (from Single AA Cell)
- Automatic Powersave Operation for light Loads
- Output Disconnect during Shutdown
- Anti-Ringing Control minimizes EMI
- Power Okay and Sense pin
- TDFN (2x2mm) 8-pin Package

3 Applications

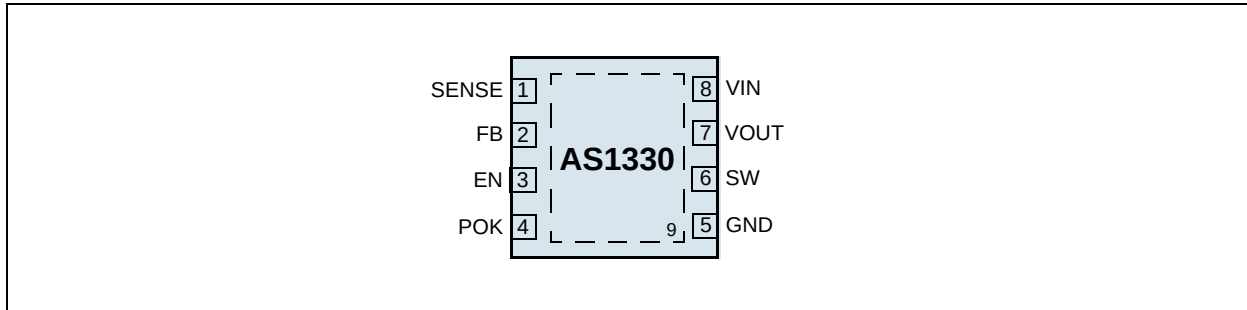
The AS1330 is ideal for space critical applications where ultra-small size is critical as in medical diagnostic equipment, hand-held instruments, digital cameras, MP3 players, GPS receivers, and PC or Memory cards.

Figure 1. AS1330 - Typical Application Diagram



4 Pin Assignments

Figure 2. Pin Assignments (Top View)



Pin Descriptions

Table 1. Pin Descriptions

Pin Number	Pin Name	Description
1	SENSE	Sense Input. Represents the input for the Power-OK behaviour. This input can be used to supervise the input or the output voltage via a resistor divider. If connected to GND the POK output is related to V _{OUT} .
2	FB	Feedback Pin. Feedback input to the g _m error amplifier. Connect a resistor divider tap to this pin. The output voltage can be adjusted from 1.8 to 3.3V by: $V_{OUT} = 0.8V[1 + (R_1/R_2)]$ If the fixed output voltage version is used, connect this pin to V _{OUT} .
3	EN	Active-High Enable Input. A logic LOW reduces the supply current to < 1μA. Connect to pin VIN for normal operation.
4	POK	Power-OK Output. Active-High, open-drain output indicates an out-of-regulation condition. Connect a 100kΩ pull-up resistor to pin OUT for logic levels. Leave this pin unconnected if the Power-OK feature is not used. Low Level: High Level:
5	GND	Signal and Power Ground. Provide a short, direct PCB path between this pin and the negative side of the output capacitor(s).
6	SW	Switch Pin. Connect an inductor between this pin and V _{IN} . Keep the PCB trace lengths as short and wide as is practical to reduce EMI and voltage overshoot. If the inductor current falls to zero, or pin EN is low, an internal 100Ω anti-ringing switch is connected from this pin to V _{IN} to minimize EMI. Note: An optional Schottky diode can be connected between this pin and V _{OUT} .
7	VOUT	Output Voltage. Bias is derived from V _{OUT} when V _{OUT} exceeds V _{IN} . PCB trace length from V _{OUT} to the output filter capacitor(s) should be as short and wide as is practical.
8	VIN	Input Voltage. The AS1330 gets its start-up bias from V _{IN} unless V _{OUT} exceeds V _{IN} , in which case the bias is derived from V _{OUT} . Thus, once started, operation is completely independent from V _{IN} . Operation is only limited by the output power level and the internal series resistance of the supply.
9		Exposed Pad. The exposed pad must be connected to GND. Ensure a good connection to the PCB to achieve optimal thermal performance.

5 Absolute Maximum Ratings

Stresses beyond those listed in [Table 2](#) may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in [Section 6 Electrical Characteristics on page 4](#) is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 2. Absolute Maximum Ratings

Parameter	Min	Max	Units	Notes
All Pins to GND	-0.3	5	V	
Operating Temperature Range	-40	+85	°C	
Storage Temperature Range	-65	+125	°C	
Latch-Up	-100	100	mA	@85°C, JEDEC 78
ESD	2		kV	HBM MIL-Std. 883E 3015.7 methods
Package Body Temperature		+260	°C	The reflow peak soldering temperature (body temperature) specified is in accordance with IPC/JEDEC J-STD-020D "Moisture/Reflow Sensitivity Classification for Non-Hermetic Solid State Surface Mount Devices". The lead finish for Pb-free leaded packages is matte tin (100% Sn).

6 Electrical Characteristics

$V_{IN} = +1.2V$, $V_{OUT} = +3.0V$, $V_{EN} = +1.3V$, $L = 1\mu H$, $C1 = C2 = 10\mu F$, $T_{AMB} = -40^{\circ}C$ to $+85^{\circ}C$ (unless otherwise specified). Typ values @ $T_{AMB} = +25^{\circ}C$.

Table 3. Electrical Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Units
Input						
	Minimum Start-Up Voltage	$I_{OUT} = 1mA$		0.85	0.9	V
V_{IN}	Operating Voltage Range ¹	$I_{OUT} = 1mA$	0.6		3.0	V
Regulation						
V_{OUT}	Output Voltage Adjust Range ²		1.8		3.0	V
	Output Voltage Accuracy	$V_{OUT} > V_{IN} + 0.6V$	-3		+3	%
V_{FB}	Feedback Voltage	for adjustable V_{OUT} only	0.776	0.8	0.824	V
I_{FB}	Feedback Input Current	$V_{FB} = 0.8V$		10		nA
Operating Current						
I_{QPWS}	Quiescent Current (Powersave Operation)	$V_{OUT} = 3.15V$		30	50	μA
I_{QSHDN}	Quiescent Current (Shutdown)	$V_{EN} = 0V$		0.05	5	μA
I_Q	Quiescent Current (Active)	in continuous mode		3		mA
Switches						
I_{LKN}	NMOS Switch Leakage	$V_{SW} = 3.6V$		0.1	5	μA
I_{LKP}	PMOS Switch Leakage ³	$V_{SW} = V_{OUT} = 3.6V$		0.1	5	μA
R_{ONNMOS}	NMOS Switch On Resistance			0.25		Ω
R_{ONPMOS}	PMOS Switch On Resistance			0.35		Ω
I_{NMOS}	NMOS Current Limit			650		mA
	Maximum Duty Cycle ¹		80	87		%
f_{SW}	Switching Frequency		3.2	4	4.8	MHz
Shutdown						
V_{ENH}	EN Input High	no load	1.2			V
V_{ENL}	EN Input Low	no load			0.25	V
I_{EN}	EN Input Current ⁴			1	1.5	μA
Power-OK⁵						
	POK Voltage Low	$I_{POK} = 1mA$		0.1	0.4	V
	POK Leakage Current	$V_{POK} = 3V$, $T_{AMB} = 25^{\circ}C$		1	100	nA
	Power-OK Threshold	Monitor V_{IN} , Falling Edge	0.72		0.76	V
		Monitor V_{OUT} , Falling Edge	90	92.5	95	%

1. Guaranteed by design and verified in lab characterisation.
2. External Schottky diode is mandatory for output voltages higher than 3V.
3. V_{OUT} is forced to 3.6V in production test.
4. Internal pull-down resistor.
5. The POK parameters are tested with proprietary test modes.

Note: All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods.

7 Typical Operating Characteristics

$V_{IN} = 1.2V$, $V_{OUT} = 1.8V$, $L = 1\mu H$, $C1 = C2 = 10\mu F$, $T_{AMB} = +25^\circ C$ (unless otherwise specified);

Figure 3. Efficiency vs. Output Current, $V_{OUT} = 1.8V$

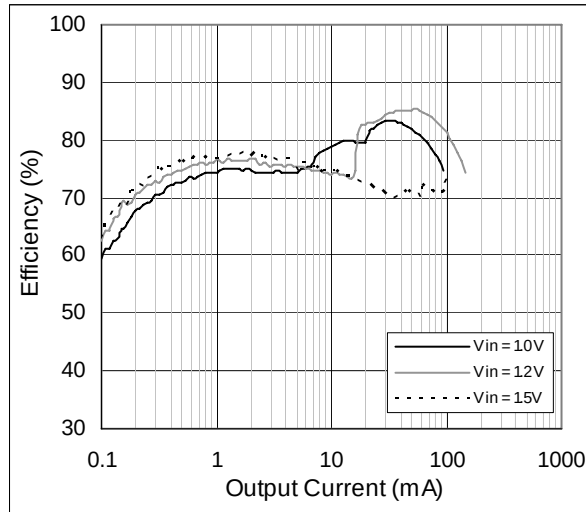


Figure 4. Efficiency vs. Input Voltage, $V_{OUT} = 1.8V$

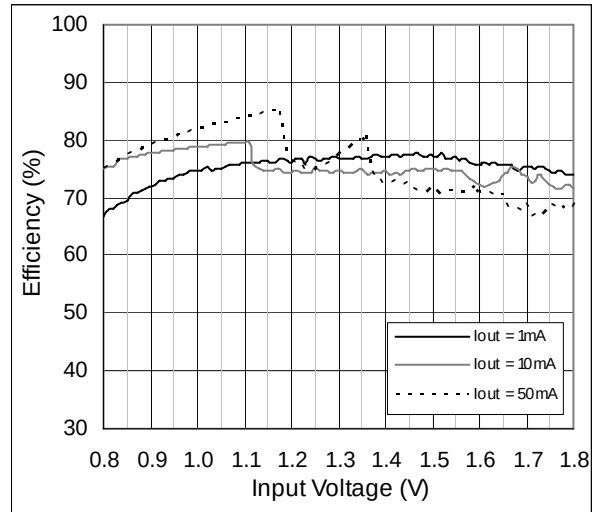


Figure 5. Efficiency vs. Output Current, $V_{OUT} = 3.0V$

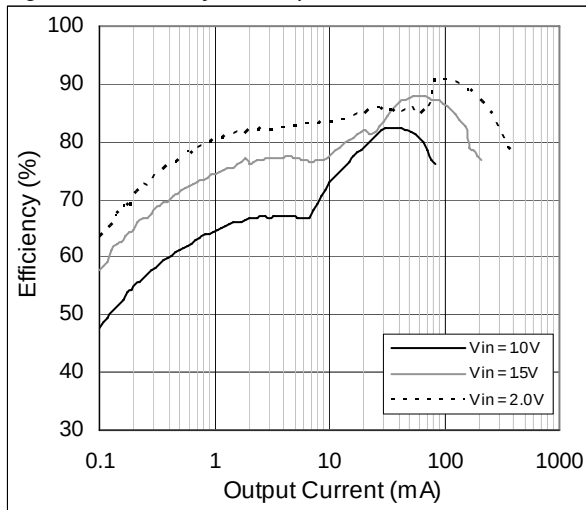


Figure 6. Efficiency vs. Input Voltage, $V_{OUT} = 3.0V$

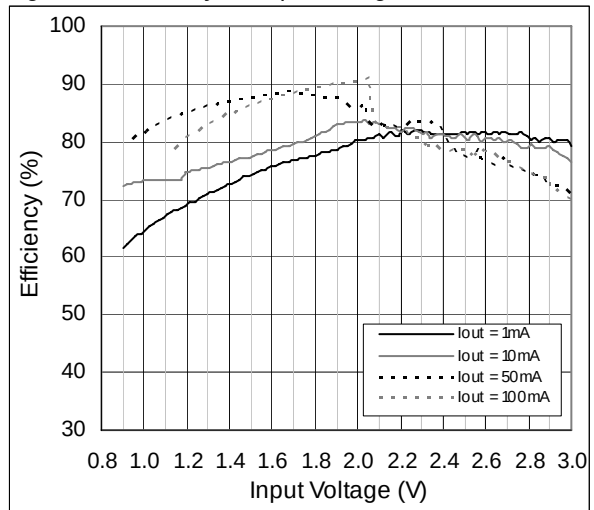


Figure 7. Efficiency vs. I_{OUT} , Coil Comparison

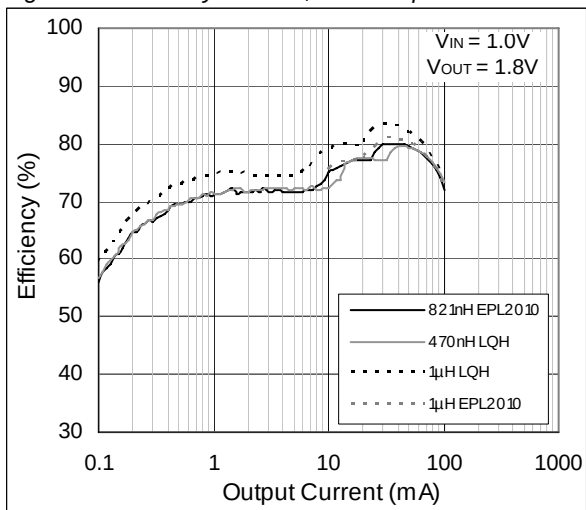


Figure 8. Efficiency vs. I_{OUT} , Coil Comparison

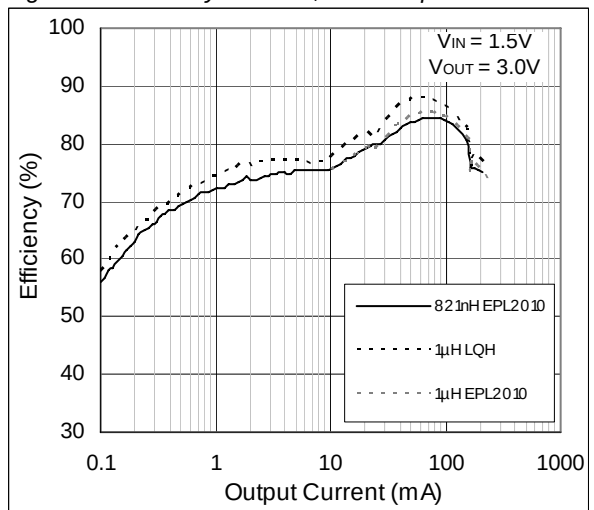


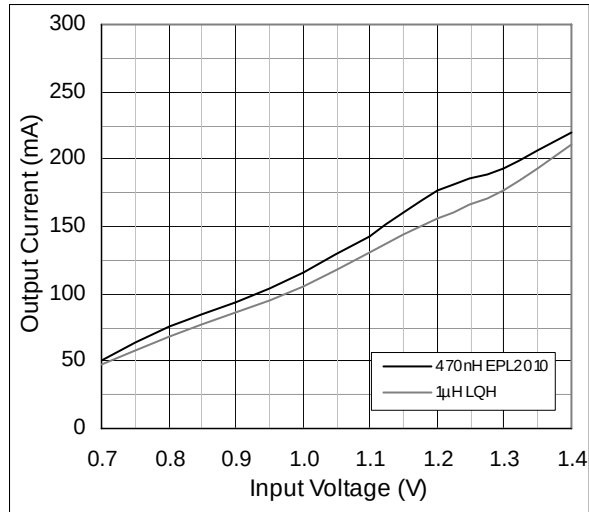
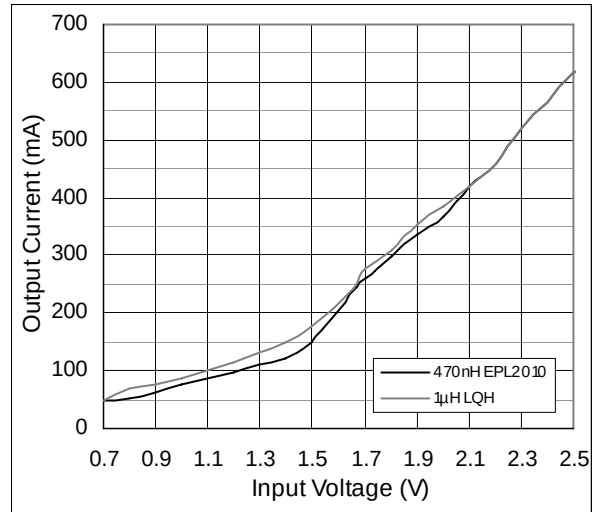
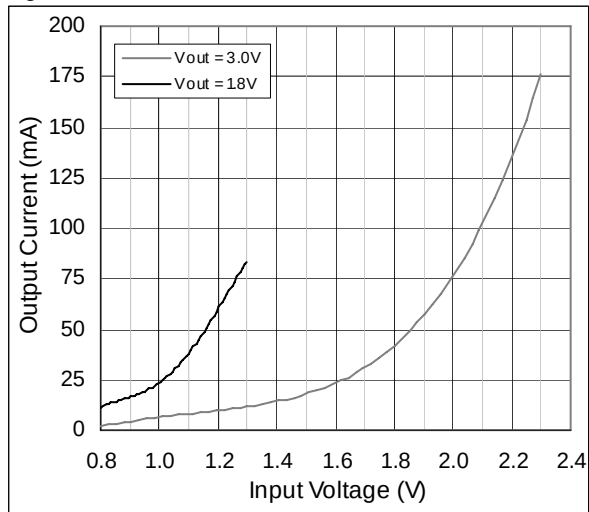
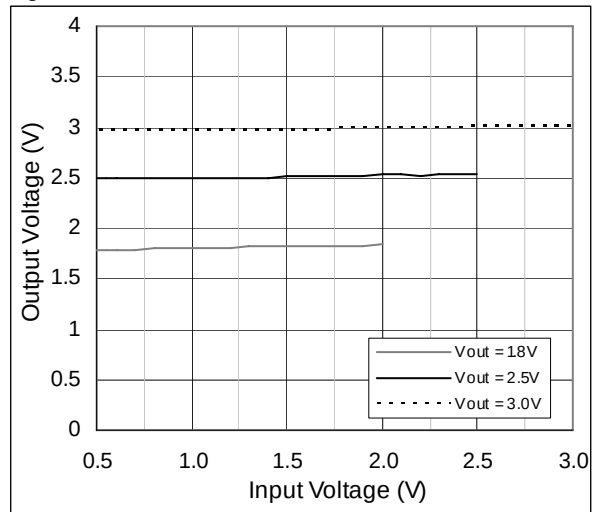
Figure 9. I_{OUT} vs. V_{IN} ; $V_{OUT} = 1.8V$ Figure 10. I_{OUT} vs. V_{IN} ; $V_{OUT} = 3.0V$ Figure 11. Powersave Threshold vs. V_{IN} Figure 12. V_{OUT} vs. V_{IN} ; $I_{OUT} = 1mA$ 

Figure 13. Startup Voltage vs. Output Current

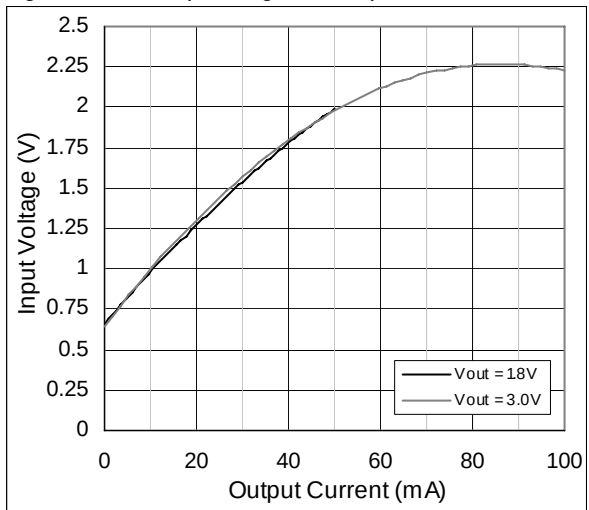


Figure 14. Input Current vs. Input Voltage

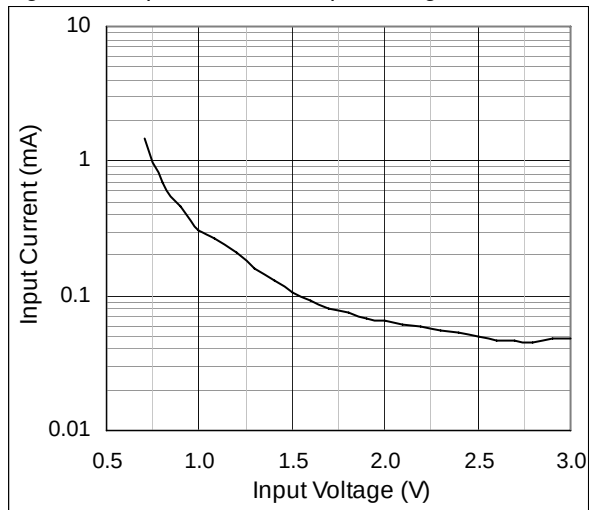
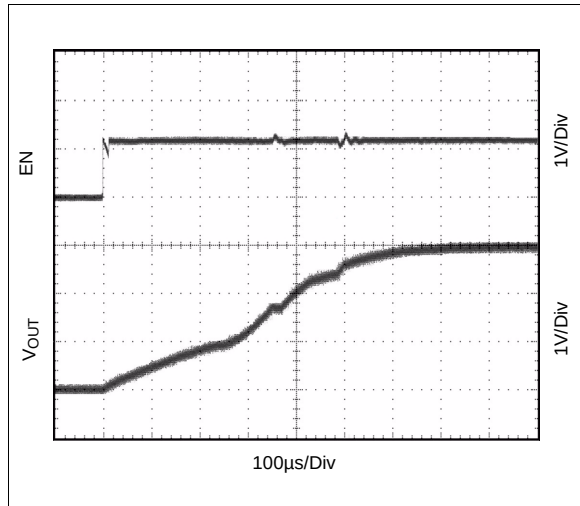
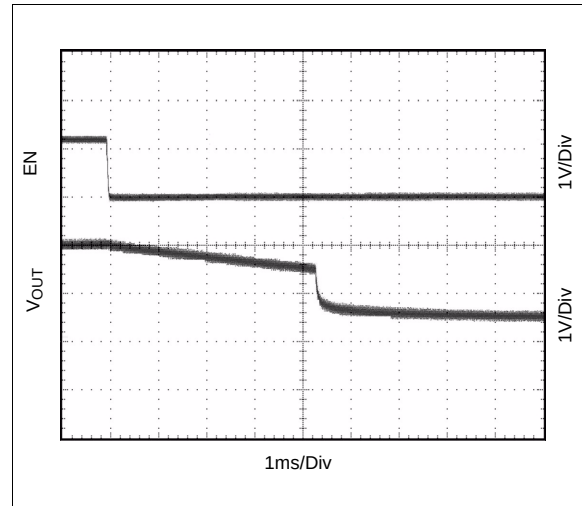
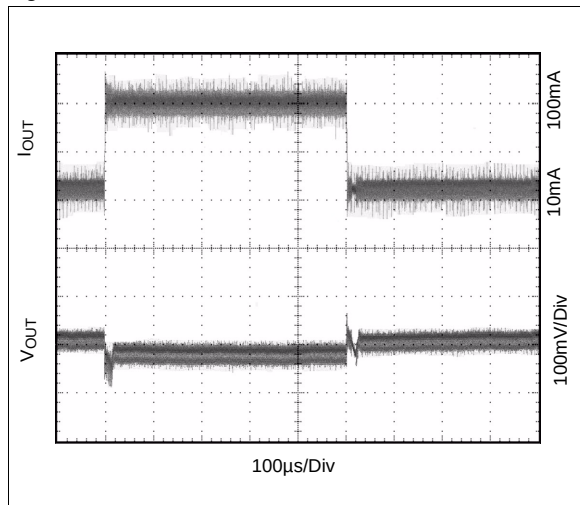
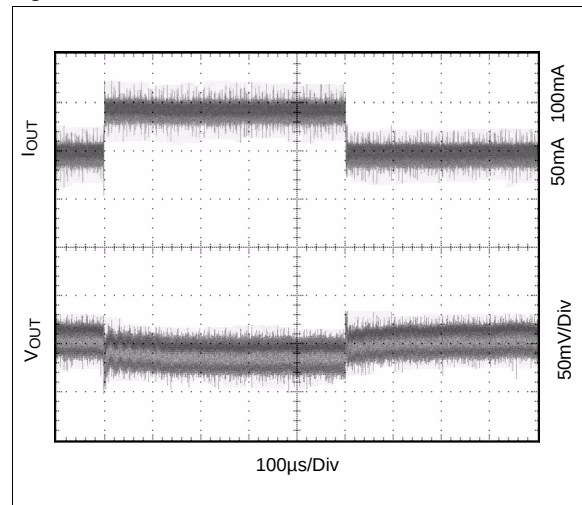


Figure 15. Startup, $V_{OUT} = 3V$, $I_{OUT} = 1mA$ Figure 16. Shutdown, $V_{OUT} = 3V$, $I_{OUT} = 1mA$ Figure 17. Load Transient, $V_{OUT} = 3V$ Figure 18. Load Transient, $V_{OUT} = 3V$ 

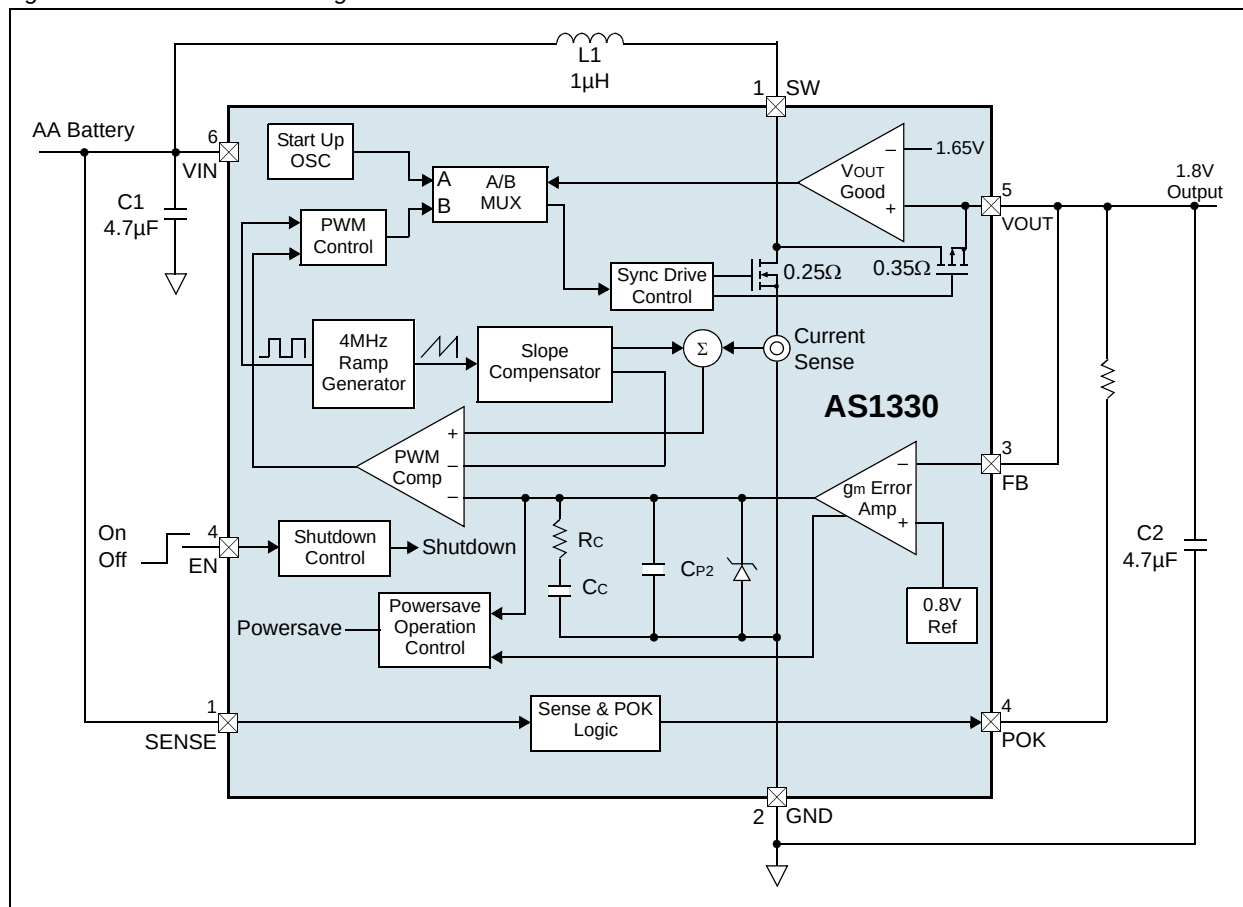
8 Detailed Description

The AS1330 can operate from a single-cell input voltage (V_{IN}) below 1V, and features fixed frequency (4MHz) and current mode PWM control for exceptional line- and load-regulation. With low $R_{DS(ON)}$ and gate charge internal NMOS and PMOS switches, the device maintains high-efficiency from light to heavy loads.

Modern portable devices frequently spend extended time in low-power or standby modes, switching to high power-drain only when certain functions are enabled. The AS1330 is ideal for portable devices since it maintain high-power conversion efficiency over a wide output power range, thus increasing battery life in these types of devices.

In addition to high-efficiency at moderate and heavy loads, the AS1330 includes an automatic powersave mode that improves efficiency of the power converter at light loads. The powersave mode is initiated if the output load current falls below a factory programmed threshold.

Figure 19. AS1330 - Block Diagram



Low-Voltage Start-Up

The AS1330 requires V_{IN} of only 0.85V (typ) or higher to start up. The low-voltage start-up circuitry controls the internal NMOS switch up to a maximum peak inductor current of 650mA (typ), with 1.5ms (approx.) off-time during start-up, allowing the devices to start up into an output load.

With a $V_{OUT} > 1.65V$, the start-up circuitry is disabled and normal fixed-frequency PWM operation is initiated. In this mode, the AS1330 operates independent of V_{IN} , allowing extended operating time as the battery can drop to several tenths of a volt without affecting output regulation. The limiting factor for the application is the ability of the battery to supply sufficient energy to the output.

Low-Noise Fixed-Frequency Operation

Oscillator

The AS1330 switching frequency is internally fixed at 4MHz allowing the use of very small external components.

Current Sensing

A signal representing the internal NMOS-switch current is summed with the slope compensator. The summed signal is compared to the error amplifier output to provide a peak current control command for the PWM. Peak switch current is limited to approximately 650mA independent of V_{IN} or V_{OUT} .

Zero Current Comparator

The zero current comparator monitors the inductor current to the output and shuts off the PMOS synchronous rectifier once this current drops to 20mA (approx.). This prevents the inductor current from reversing polarity and results in improved converter efficiency at light loads.

Anti-Ringing Control

Anti-ringing control circuitry prevents high-frequency ringing on pin SW as the inductor current approaches zero. This is accomplished by damping the resonant circuit formed by the inductor and the capacitance on pin SW (C_{sw}).

Powersave Operation

In light load conditions, the integrated powersave feature removes power from all circuitry not required to monitor V_{OUT} . When V_{OUT} has dropped approximately 1% from nominal, the device powers up and begins normal PWM operation.

C_2 recharges, causing the AS1330 to re-enter powersave mode as long as the output load remains below the powersave threshold. The frequency of this intermittent PWM is proportional to load current; i.e., as the load current drops further below the powersave threshold, the AS1330 turns on less frequently. When the load current increases above the powersave threshold, the AS1330 will resume continuous, seamless PWM operation.

Notes:

1. An optional capacitor (C_{FF}) between pins V_{OUT} and FB in some applications can reduce V_{OUTp-p} ripple and input quiescent current during powersave mode. Typical values for C_{FF} range from 15 to 220pF.
2. In powersave mode the AS1330 draws only 30 μ A from the output capacitor(s), greatly improving converter efficiency.

Shutdown

When pin EN is low the AS1330 is switched off and <1 μ A current is drawn from the battery; when pin EN is high the device is switched on. If EN is driven from a logic-level output, the logic high-level (on) should be referenced to V_{OUT} to avoid intermittently switching the device on.

In shutdown the battery input is disconnected from the output.

Thermal Overload Protection

To prevent the AS1330 from short-term misuse and overload conditions the chip includes a thermal overload protection. To block the normal operation mode the device is turning the PFET and the NFET off in PWM mode as soon as the junction temperature exceeds 150°C. To resume the normal operation the temperature has to drop below 140°C.

Note: Continuing operation in thermal overload conditions may damage the device and is considered bad practice.

9 Application Information

The AS1330 is ideal for space critical applications where ultra-small size is critical as in medical diagnostic equipment, hand-held instruments, digital cameras, MP3 players, GPS receivers, and PC or Memory cards.

Along with [Figure 1 on page 1](#), [Figure 20](#), [Figure 21](#) and [Figure 22 on page 11](#) depict a few of the many applications for which the AS1330 converters are perfectly suited.

Adjustable Output Voltage

The integrated error amplifier is an internally compensated trans-conductance (g_m) type (current output). The internal 0.8V reference voltage is compared to the voltage at pin FB to generate an error signal at the output of the error amplifier. A voltage divider from V_{OUT} to GND programs the output voltage from 1.8 to 3.0V via pin FB as:

$$V_{OUT} = 0.8V(1 + (R_1/R_2)) \quad (EQ\ 1)$$

Sense Function

The AS1330 offers a sense function for monitoring a voltage (e.g.: the battery voltage). The sense function can work in three different modes:

- SENSE to GND: The POK is related to V_{OUT} ([see Figure 22 on page 11](#)).
- SENSE to V_{IN} : If the pin SENSE is directly connected to pin V_{IN} , the internal reference voltage (0.8V) is used to compare it with V_{IN} . The POK goes high when the voltage on SENSE is above 0.8V and low when the voltage on SENSE is below 0.8V ([see Figure 21 on page 11](#)).
- SENSE to a voltage divider: With the voltage divider the threshold voltage on which the POK reacts can be set. If the monitored voltage is higher than the user set threshold voltage the POK is high, when the monitored voltage is lower the POK goes low ([see Figure 20](#)). The threshold voltage can be set with the following equation:

$$V_{threshold} = 0.8V(1 + (R_{IN1}/R_{IN2})) \quad (EQ\ 2)$$

Figure 20. AS1330 - Boost Converter, Single AA Cell to 3.0V fixed Output Voltage

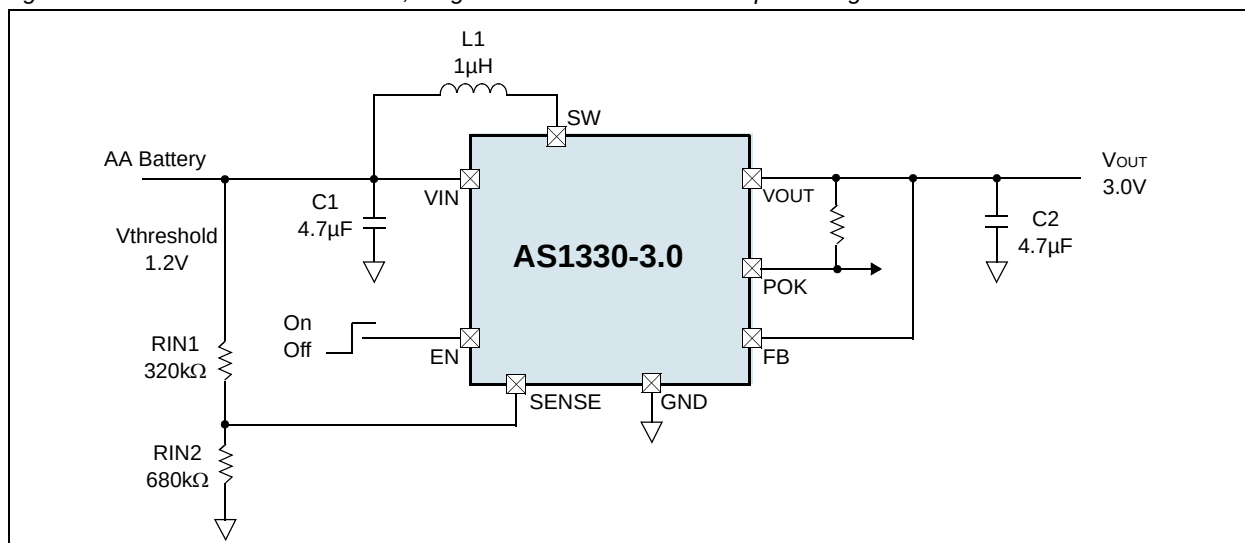
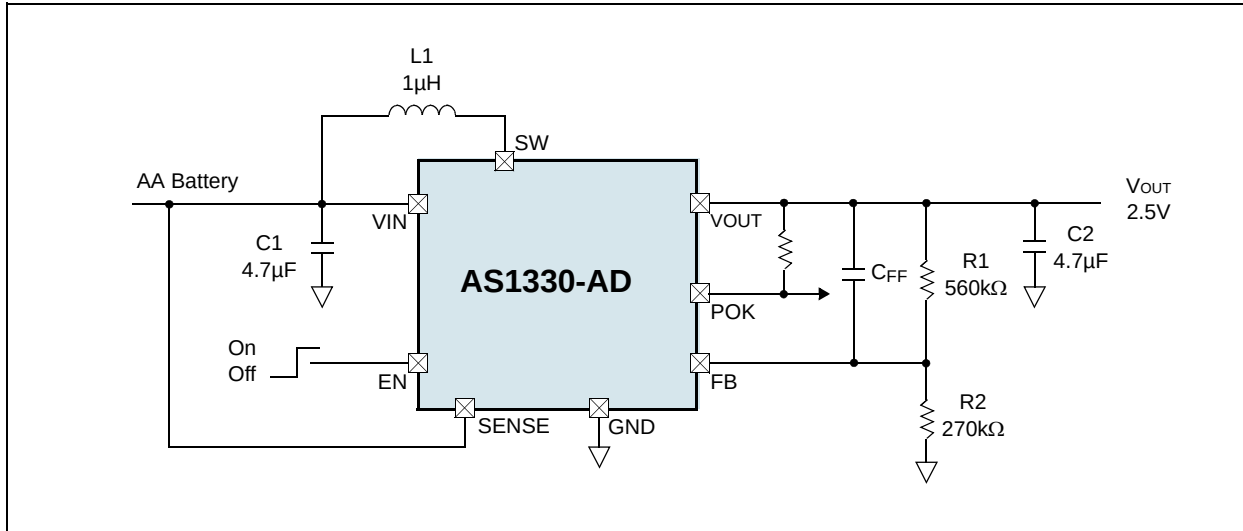
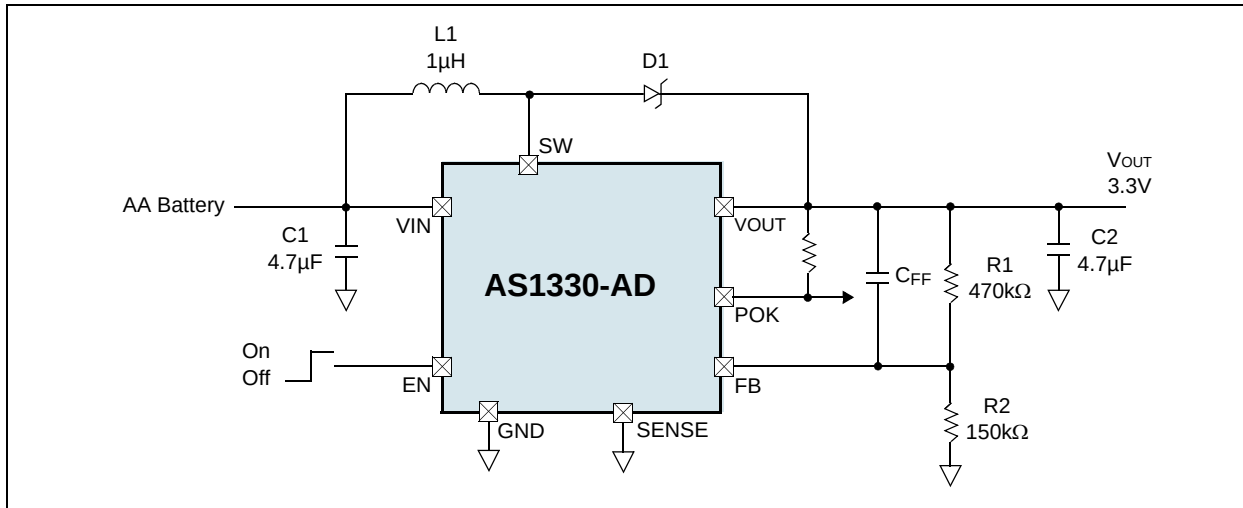


Figure 21. AS1330 - Boost Converter, Single AA Cell to 2.5V adjustable Output Voltage



To power an output voltage of 3.3V with the AS1330 a schottky diode is required. In this setup the output disconnect function is no longer working because the schottky diode is bypassing the input to the output.

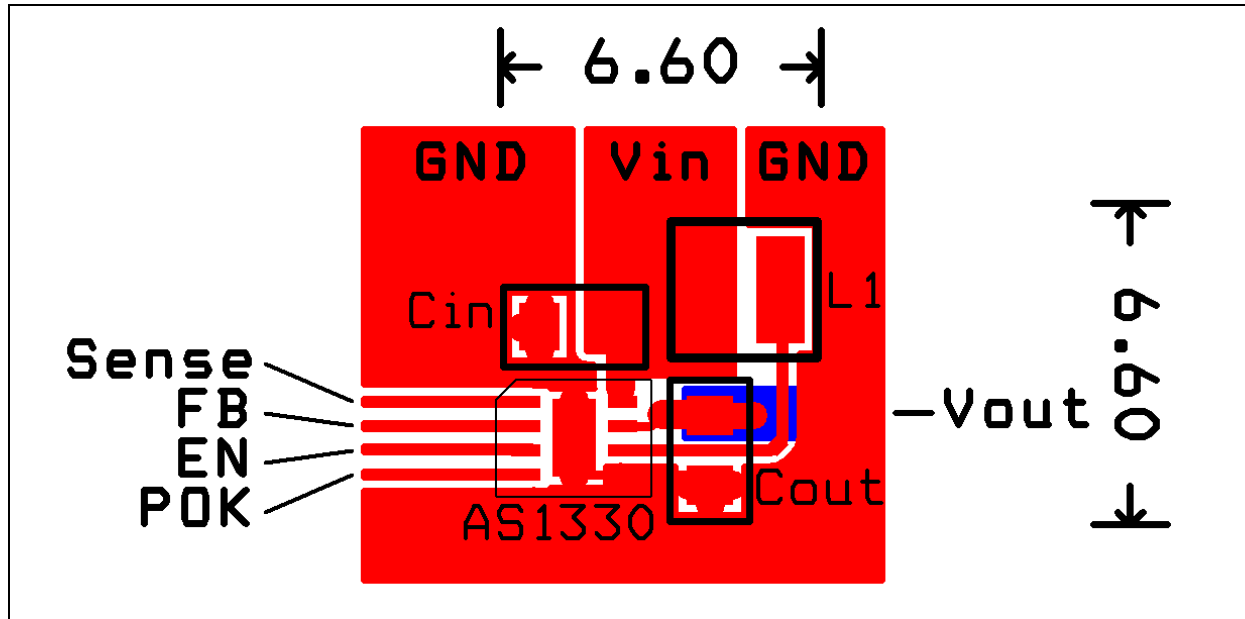
Figure 22. AS1330 - Boost Converter, Single AA Cell to 3.3V adjustable Output Voltage



Smallest Layout

Due to the high switching frequency, the small package and the minimal count of external components, the overall DC-DC system requires only 6.6x6.6mm of PCB space (see Figure 23).

Figure 23. Layout Consideration



Component Selection

Only three power components are required to complete the design of the boost converter, except the additional two resistors for the voltage divider to set V_{OUT} . The high operating frequency and low peak currents of the AS1330 allow the use of low value, low profile inductors and tiny external ceramic capacitors.

Inductor Selection

The inductor should have low ESR to reduce the I^2R power losses, and must be able to handle the peak inductor current without saturating. High-frequency ferrite core inductor materials reduce frequency dependent power losses compared to less expensive powdered iron types, which result in improved converter efficiency.

A 1 μ H inductor with a >850mA current rating and low DCR is recommended. For applications where radiated noise is a concern, a toroidal or shielded inductor can be used.

Capacitor Selection

A 4.7 μ F capacitor is recommended for C1 and for C2. Small-sized ceramic capacitors are recommended. X5R and X7R ceramic capacitors are recommended as they retain capacitance over wide ranges of voltages and temperatures.

Output Capacitor Selection

Low ESR capacitors should be used to minimize V_{OUT} ripple. Multi-layer ceramic capacitors are recommended since they have extremely low ESR and are available in small footprints. Up to 10 μ F output capacitor is sufficient for most applications. Larger values up to 22 μ F may be used to obtain extremely low output voltage ripple and improve transient response.

An additional phase lead capacitor may be required with output capacitors larger than 10 μ F to maintain acceptable phase margin. X5R and X7R dielectric materials are recommended due to their ability to maintain capacitance over wide voltage and temperature ranges.

Input Capacitor Selection

Low ESR input capacitors reduce input switching noise and reduce the peak current drawn from the battery. Ceramic capacitors are recommended for input decoupling and should be located as close to the device as is practical. A 4.7 μ F input capacitor is sufficient for most applications. Larger values may be used without limitations.

Table 4. Recommended External Components

Name	Part Number	Value	Rating	Type	Size	Manufacturer
C1, C2	GRM219R60J106KE19	10 μ F	6.3V	X5R	0805	Murata www.murata.com
	GRM188R60J475KE19	4.7 μ F	6.3V	X5R	0603	
L1	LQH32PN1R0NN0	1 μ H	2.05A	45m Ω	3.2x2.5x1.55mm	Coilcraft www.coilcraft.com
	LQH32PNR47NN0	470nH	2.55A	30m Ω	3.2x2.5x1.55mm	
	EPL2010-102ML	1 μ H	1.35A	99m Ω	2.0x2.0x1.0mm	
	EPL2010-821ML	820nH	1.6A	68m Ω	2.0x2.0x1.0mm	
	EPL2010-471ML	470nH	2.2A	40m Ω	2.0x2.0x1.0mm	

Diode Selection

A Schottky diode should be used to carry the output current for the time it takes the PMOS synchronous rectifier to switch on. For $V_{OUT} > 3.0V$ a schottky diode is mandatory, for $V_{OUT} \leq 3.0V$ it is optional, although using one will increase device efficiency by 2 to 3%. On one hand the schottky diode reduces the overshoot on the output signal but on the other hand the output disconnect function is no longer working.

Note: Do not use ordinary rectifier diodes, since the slow recovery times will compromise efficiency.

10 Package Drawings and Markings

The device is available in a TDFN (2x2mm) 8-pin package.

Figure 24. TDFN (2x2mm) 8-pin package Diagram

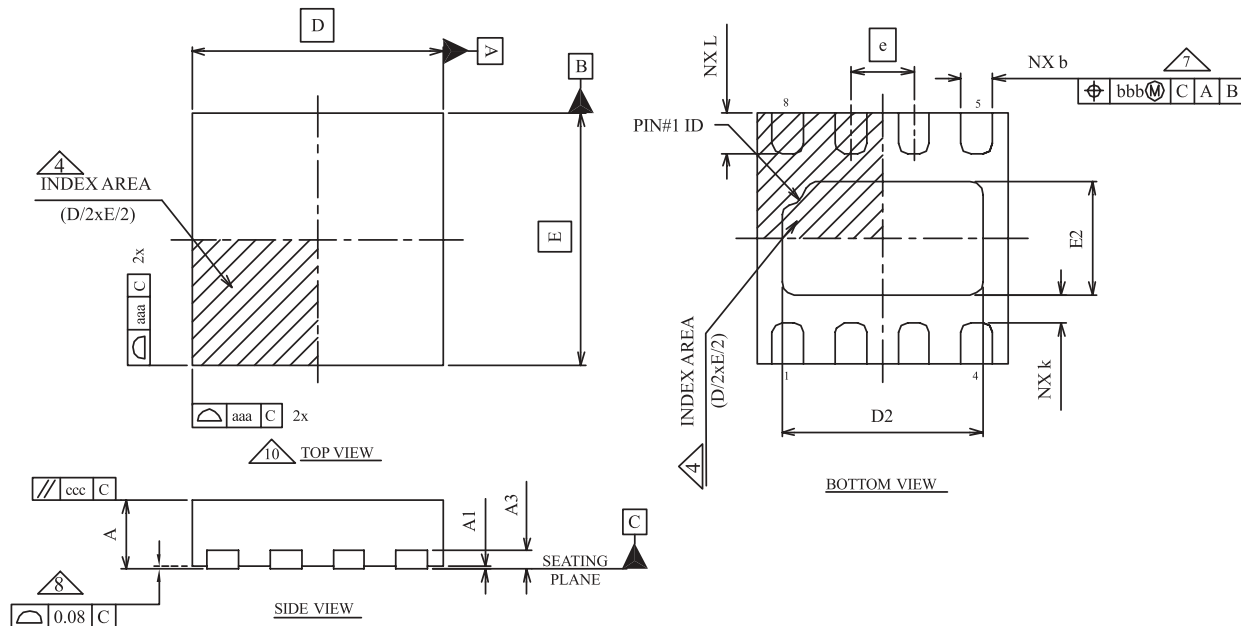


Table 5. TDFN (2x2mm) 8-pin package Dimensions

Symbol	Min	Typ	Max	Symbol	Min	Typ	Max
A	0.51	0.55	0.60	D		2.00	
A1	0.00	0.02	0.05	E		2.00	
A3		0.15 ref		D2	1.45	1.60	1.70
aaa		0.15		E2	0.75	0.90	1.00
bbb		0.10		L	0.225	0.325	0.425
ccc		0.10		N		8	
k	0.20			ND		4	
b	0.20	0.25	0.30	NE		--	
e		0.50					

Note:

3. Dimensioning and tolerancing conform to ASME Y14.5M-1994.
4. All dimensions are in millimeters, angle is in degrees.
5. Terminal #1 identifier and terminal numbering convention shall conform to JESD 95-1 SPP-012. Details of terminal #1 identifier are optional, but must be located within the area indicated. The terminal #1 identifier may be either a mold, embedded metal or mark feature.
6. Dimension **b** applies to metallized terminal and is measured between 0.15 and 0.30mm from terminal tip.

11 Ordering Information

The device is available as the standard products listed in [Table 6](#).

Table 6. Ordering Information

Ordering Code	Marking	Output	Description	Delivery Form	Package
AS1330-BTDT-AD	AV	adjustable	4MHz, Low Voltage, DC-DC Step-Up Converter	Tape and Reel	TDFN (2x2mm) 8-pin
AS1330-BTDT-18	AU	1.8V	4MHz, Low Voltage, DC-DC Step-Up Converter	Tape and Reel	TDFN (2x2mm) 8-pin
AS1330-BTDT-30	AZ	3.0V	4MHz, Low Voltage, DC-DC Step-Up Converter	Tape and Reel	TDFN (2x2mm) 8-pin

Note: All products are RoHS compliant and Pb-free.

Buy our products or get free samples online at ICdirect: <http://www.austriamicrosystems.com/ICdirect>

For further information and requests, please contact us <mailto:sales@austriamicrosystems.com>
or find your local distributor at <http://www.austriamicrosystems.com/distributor>

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